L	Hits	Search Text	DB	Time stamp
Number		(242/44) 777		0004/00/04
15	234	(349/114).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:48
			EPO; JPO;	
1.0	1400	(240 (42) GGT G	DERWENT	2004/00/04
16	1492	(349/42).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:48
			EPO; JPO;	
17	1042	(349/138).CCLS.	DERWENT USPAT;	2004/08/04
1 /	1042	(349/130).0013.	US-PGPUB;	13:49
			EPO; JPO;	13.49
			DERWENT	
18	1006	(349/43).CCLS.	USPAT;	2004/08/04
10	1000	(343/43):00LB:	US-PGPUB;	13:49
			EPO; JPO;	13.45
			DERWENT	
19	194	(349/44).CCLS.	USPAT;	2004/08/04
		(,,	US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
20	1553	(257/59).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
21	1442	(257/72).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
22	1006	(349/43).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
23	461	((257/59).CCLS.) and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	13:52
		adj2 resin) same (passivation passivating	EPO; JPO;	
24	396	insulation insulating) near2 (film layer)	DERWENT	2004/00/04
24	396	(((257/72).CCLS.) and (switching adj2	USPAT;	2004/08/04
		<pre>element TFT)) and (insulat\$3 passivat\$3) same organic and pixel</pre>	US-PGPUB; EPO; JPO;	13:52
		same organic and prizer	DERWENT	
25	335	 (liquid adj crystal adj display LCD) and	USPAT;	2004/08/04
		reflective and (insulating passivation)	US-PGPUB;	13:52
		adj2 layer same organic and (switching	EPO; JPO;	
1		adj2 element TFT)	DERWENT	
27	280	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	13:54
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
		and reflector		
28	168	(349/46).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:54
			EPO; JPO;	
			DERWENT	
26	379	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:06
		adj2 resin) same (passivation passivating	EPO; JPO;	
1		insulation insulating) near2 (film layer)	DERWENT	
}		and reflective near2 (electrode film		
29	426	layer) ((349/43).CCLS.) and (organic BCB	IIGDAT.	2004/08/04
43	44.0	acrylic) same (insulat\$3 passivat\$3)	USPAT;	14:39
1		acryrro, same (rusuracis passivacis)	US-PGPUB; EPO; JPO;	14.05
			DERWENT	
	L		~ T1/44 T14 T	

30	409	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:12
1		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
		and (transflective transflector		
		transreflective reflective near2		
		(electrode film layer))		
31	147	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:12
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
		and (transflective transflector		
		transreflective)		